



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



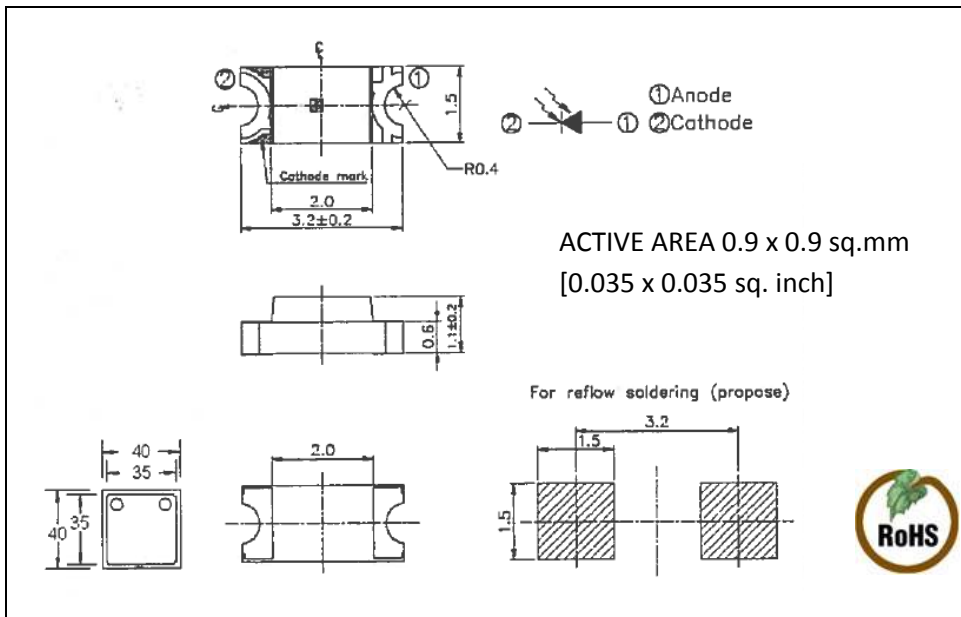
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FEATURES

- Small Footprint
- Low Capacitance
- High Speed

DESCRIPTION

The **SD040-111-411** is a Silicon Photodiode assembled in a 1206 SMT package.

APPLICATIONS

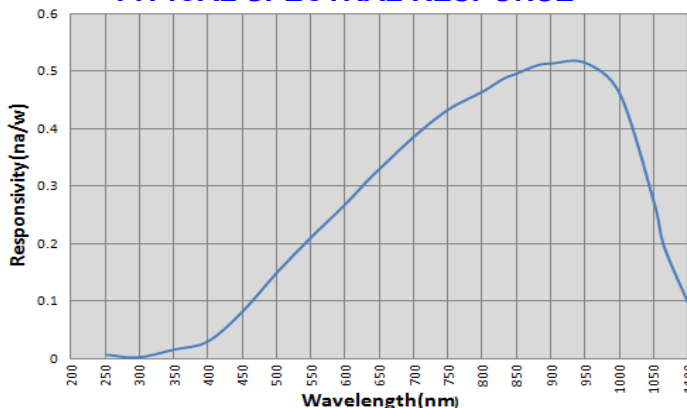
- Industrial Sensors
- Light Management
- Handheld Devices

ABSOLUTE MAXIMUM RATING

T_a = 25°C UNLESS OTHERWISE NOTED

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _R	Reverse Voltage		50	V
T _{Op}	Operating Temperature	-40	+105	°C
T _{Stg}	Storage Temperature	-50	+125	°C
T _S	Soldering Temperature		+260	°C

TYPICAL SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS RATING

T_a = 25°C, UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
V _f	Forward Voltage	I _f = 10 mA	0.5	0.8	1.3	V
I _L	Light Current (2856K)	V _R = 5V; H = 1000 lux	-	9.0	-	µA
V _{br}	Breakdown Voltage	I _R = 100 µA	50	-	-	V
R _{sh}	Shunt Resistance	V _{bias} = 10 mV	-	1.0	-	GΩ
I _d	Dark Current	V _R = 10 V	-	-	0.5	nA
C _j	Junction Capacitance	V _R = 5V; f = 1000 kHz	-	20	-	pF

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